NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE30H15 uses advanced trench technology and design to provide excellent $R_{\text{DS}(\text{ON})}$ with low gate charge. It can be used in a wide variety of applications.

General Features

● V_{DS} =30V,I_D =150A

 $R_{DS(ON)}$ <3.0 m Ω @ V_{GS} =10V

 $R_{DS(ON)}$ <4.0m Ω @ V_{GS} =4.5V

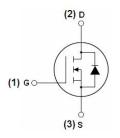
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% AVds TESTED!



Schematic diagram



Marking and pin assignment



TO-220-3L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE30H15	NCE30H15	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_c=25 ℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	30	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	150	Α
Drain Current-Continuous(Tc=100℃)	I _D (100℃)	105	Α
Pulsed Drain Current	I _{DM}	600	Α
Maximum Power Dissipation	P _D	130	W
Derating factor		0.87	W/℃
Single pulse avalanche energy (Note 5)	Eas	1700	mJ
Repetitive avalanche energy (Note 6)	E _{AR}	400	mJ



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NCE30H15

Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$ C	
Thermal Characteristic				
Thermal Resistance,Junction-to-Case ^(Note 2)	R _{θJC}	1.15	°C/W	

Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics			•				
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	30	35	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μA	
Gate-Body Leakage Current	Igss	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.2	1.7	2.5	V	
	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	2.3	3.0	0	
Drain-Source On-State Resistance		V _{GS} =4.5V, I _D =20A	3.2 4.0		4.0	mΩ	
Forward Transconductance	G FS	V _{DS} =10V,I _D =20A	32	-	-	S	
Dynamic Characteristics (Note4)							
Input Capacitance	C _{lss}	\/ 45\/\/ 0\/	-	6297	-	PF	
Output Capacitance	Coss	V_{DS} =15V, V_{GS} =0V, F=1.0MHz	-	866	-	PF	
Reverse Transfer Capacitance	C _{rss}	F=1.UIVIHZ	-	672	-	PF	
Switching Characteristics (Note 4)		•					
Turn-on Delay Time	t _{d(on)}		-	26	-	nS	
Turn-on Rise Time	t _r	V _{DD} =15V,I _D =20A,	-	24	-	nS	
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =2.5 Ω	-	91	-	nS	
Turn-Off Fall Time	t _f		-	39	-	nS	
Total Gate Charge	Qg	\/ 45\/ L 00A	-	114		nC	
Gate-Source Charge	Q _{gs}	$V_{DS}=15V,I_{D}=20A,$ $V_{GS}=10V$	-	22		nC	
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	19		nC	
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-		1.2	V	
Diode Forward Current (Note 2)	Is		-	-	150	Α	
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 20A	-	42	-	nS	
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	39	-	nC	
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LI					

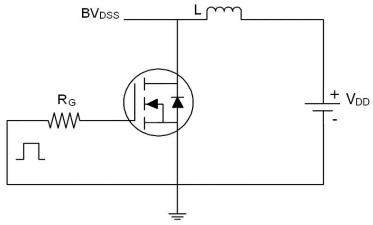
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. E_{AS} condition : Tj=25 $^{\circ}\text{C}$,V_DD=20V,VG=10V,L=0.5mH,Rg=25 Ω
- 6.Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=175°C.

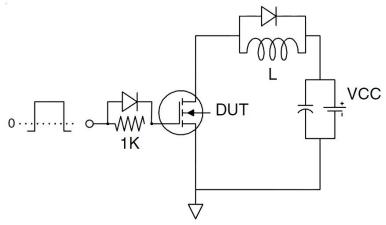
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Test circuit

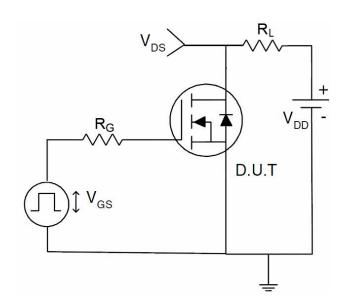
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

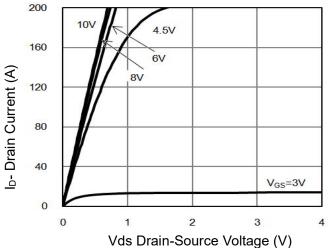


Figure 1 Output Characteristics

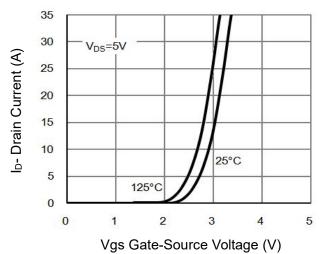


Figure 2 Transfer Characteristics

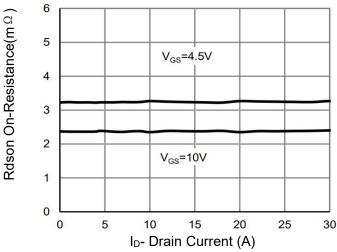


Figure 3 Rdson- Drain Current

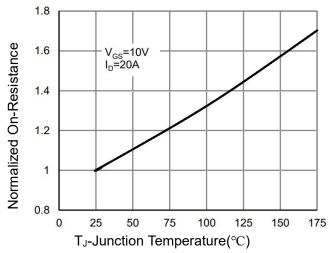


Figure 4 Rdson-JunctionTemperature

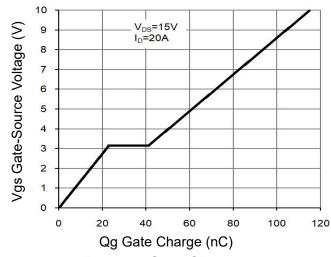


Figure 5 Gate Charge

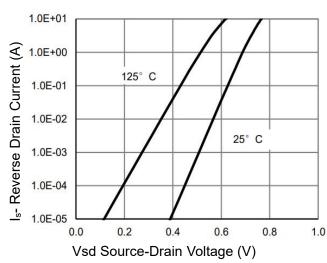


Figure 6 Source- Drain Diode Forward



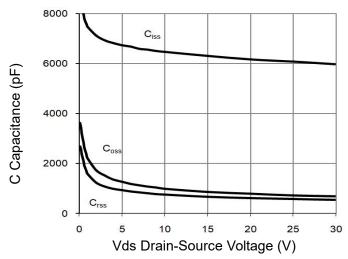


Figure 7 Capacitance vs Vds

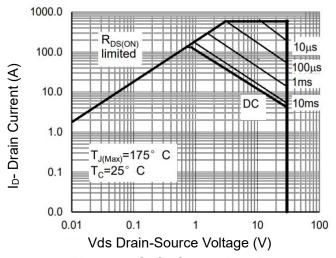


Figure 8 Safe Operation Area

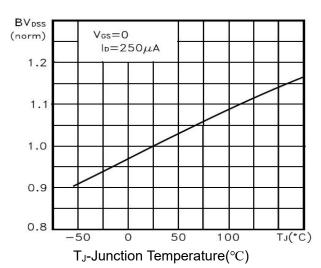


Figure 9 BV_{DSS} vs Junction Temperature

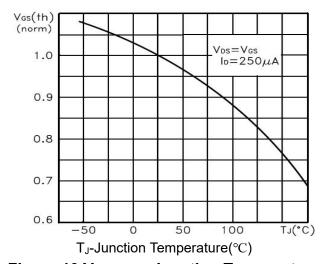


Figure 10 V_{GS(th)} vs Junction Temperature

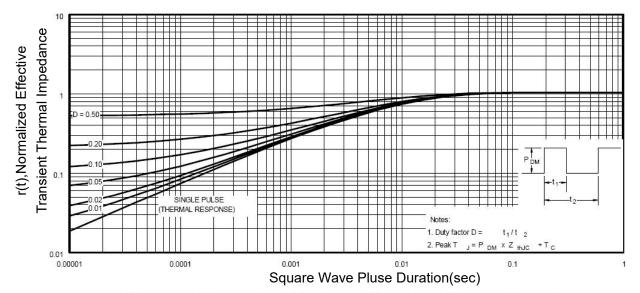
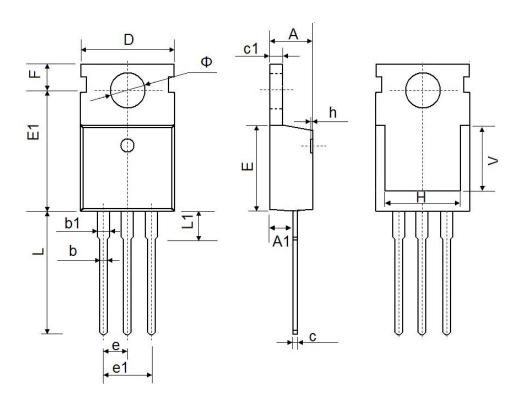


Figure 11 Normalized Maximum Transient Thermal Impedance

TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540	TYP.	0.100	TYP.	
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500	7.500 REF.		REF.	
Ф	3.400	3.800	0.134	0.150	

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